TLV2541, TLV2542, TLV2545 2.7-V TO 5.5-V, LOW-POWER, 12-BIT, 140/200 KSPS, SERIAL ANALOG-TO-DIGITAL CONVERTERS WITH AUTOPOWER DOWN

SLAS245E -MARCH 2000 - REVISED APRIL 2010

- Maximum Throughput . . . 140/200 KSPS
- Built-In Conversion Clock
- INL/DNL: ±1 LSB Max, SINAD: 72 dB, SFDR: 85 dB, f_i = 20 kHz
- SPI/DSP-Compatible Serial Interface
- Single Supply: 2.7 Vdc to 5.5 Vdc
- Rail-to-Rail Analog Input With 500 kHz BW
- Three Options Available:
 - TLV2541: Single Channel Input

- TLV2542: Dual Channels With Autosweep
- TLV2545: Single Channel With Pseudo-Differential Input
- Low Power With Autopower Down
 - Operating Current: 1 mA at 2.7 V, 1.5 mA at 5 V

Autopower Down: 2 μA at 2.7 V, 5 μA

at 5 V

Small 8-Pin MSOP and SOIC Packages

TOP VIEW TLV2541			VIEW 2542	TOP VIEW TLV2545			
cs [1 U	8 SDO	CS [1	フ_8] SDO	<u>cs</u> [1	8 SDO	
V _{REF} [2	7 🛮 FS	V _{REF} []2	7 🛛 SCLK	V _{REF} []2	7 🛚 SCLK	
GND [3	6 🛮 ∨ _{DD}	GND []3	6	GND []3	6 🛮 ∨ _{DD}	
AIN [4	5 SCLK	AINO 🛮 4	5 AIN1	AIN(+) 🛮 4	5 AIN(-)	

description

The TLV2541, TLV2542, and TLV2545 are a family of high performance, 12-bit, low power, miniature, CMOS analog-to-digital converters (ADC). The TLV254x family operates from a single 2.7-V to 5.5-V supply. Devices are available with single, dual, or single pseudo-differential inputs. Each device has a chip select (CS), serial clock (SCLK), and serial data output (SDO) that provides a direct 3-wire interface to the serial port of most popular host microprocessors (SPI interface). When interfaced with a TMS320™ DSP, a frame sync signal (FS) can be used to indicate the start of a serial data frame on CS for all devices or FS for the TLV2541.

TLV2541, TLV2542, and TLV2545 are designed to operate with very low power consumption. The power saving feature is further enhanced with an autopower-down mode. This product family features a high-speed serial link to modern host processors with SCLK up to 20 MHz. The maximum SCLK frequency is dependent upon the mode of operation (see Table 1). The TLV254x family uses the built-in oscillator as the conversion clock, providing a 3.5-µs conversion time.

AVAILABLE OPTIONS

	PACKAGED DEVICES				
T _A	8-MSOP (DGK)	8-SOIC (D)			
	TLV2541CDGK (AGZ)				
0°C to 70°C	TLV2542CDGK (AHB)				
	TLV2545CDGK (AHD)				
	TLV2541IDGK (AHA)	TLV2541ID			
-40°C to 85°C	TLV2542IDGK (AHC)	TLV2542ID			
	TLV2545IDGK (AHE)	TLV2545ID			

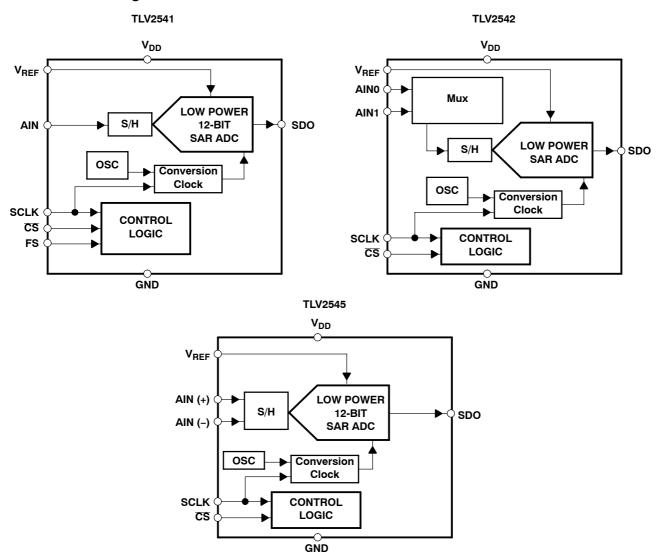


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TMS320 is a trademark of Texas Instruments.



functional block diagram



TLV2541, TLV2542, TLV2545 2.7-V TO 5.5-V, LOW-POWER, 12-BIT, 140/200 KSPS, SERIAL ANALOG-TO-DIGITAL CONVERTERS WITH AUTOPOWER DOWN

SLAS245E -MARCH 2000 - REVISED APRIL 2010

Terminal Functions

TLV2541

TERMIN	RMINAL		TERMINAL		DECORPTION
NAME	NO.	I/O	DESCRIPTION		
AIN	4	I	Analog input channel		
CS	1	I	Chip select. A high-to-low transition on the $\overline{\text{CS}}$ input removes SDO from 3-state within a maximum setup time. $\overline{\text{CS}}$ can be used as the FS pin when a dedicated DSP serial port is used.		
FS	7	I	DSP frame sync input. Indication of the start of a serial data frame. Tie this terminal to V _{DD} if not used.		
GND	3	1	Ground return for the internal circuitry. Unless otherwise noted, all voltage measurements are with respect to GND.		
SCLK	5	I	Output serial clock. This terminal receives the serial SCLK from the host processor.		
SDO	8	0	The 3-state serial output for the A/D conversion result. SDO is kept in the high-impedance state until $\overline{\text{CS}}$ falling edge or FS rising edge, whichever occurs first. The output format is MSB first.		
			When FS is not used (FS = 1 at the falling edge of \overline{CS}): The MSB is presented to the SDO pin after \overline{CS} falling edge and output data is valid on the first falling edge of SCLK.		
			When \overline{CS} and FS are both used (FS = 0 at the falling edge of \overline{CS}): The MSB is presented to the SDO pin after the falling edge of \overline{CS} . When \overline{CS} is tied/held low, the MSB is presented on SDO after the rising FS. Output data is valid on the first falling edge of SCLK. (This is typically used with an active FS from a DSP using a dedicated serial port.)		
V_{DD}	6	I	Positive supply voltage		
V_{REF}	2	I	External reference input		

TLV2542/45

TERMINA	RMINAL		TERMINAL		DECORIDEION
NAME	NO.	I/O	DESCRIPTION		
AIN0 /AIN(+)	4	I	Analog input channel 0 for TLV2542—Positive input for TLV2545.		
AIN1/AIN (-)	5	I	Analog input channel 1 for TLV2542—Inverted input for TLV2545.		
CS	1	I	Chip select. A high-to-low transition on $\overline{\text{CS}}$ removes SDO from 3-state within a maximum delay time. This pin can be connected to the frame sync of a DSP using a dedicated serial port.		
GND	3	I	Ground return for the internal circuitry. Unless otherwise noted, all voltage measurements are with respect to GND.		
SCLK	7	I	Output serial clock. This terminal receives the serial SCLK from the host processor.		
SDO	8	0	The 3-state serial output for the A/D conversion result. SDO is kept in the high-impedance state when $\overline{\text{CS}}$ is high and presents output data after the $\overline{\text{CS}}$ falling edge until the LSB is presented. The output format is MSB first. SDO returns to the Hi-Z state after the 16th SCLK. Output data is valid on the falling SCLK edge.		
V_{DD}	6	I	Positive supply voltage		
V_{REF}	2	I	External reference input		

detailed description

The TLV2541, TLV2542, and TLV2545 are successive approximation (SAR) ADCs utilizing a charge redistribution DAC. Figure 1 shows a simplified version of the ADC.

The sampling capacitor acquires the signal on AIN during the sampling period. When the conversion process starts, the SAR control logic and charge redistribution DAC are used to add and subtract fixed amounts of charge from the sampling capacitor to bring the comparator into a balanced condition. When the comparator is balanced, the conversion is complete and the ADC output code is generated.

SLAS245E -MARCH 2000 - REVISED APRIL 2010 detailed description (continued)

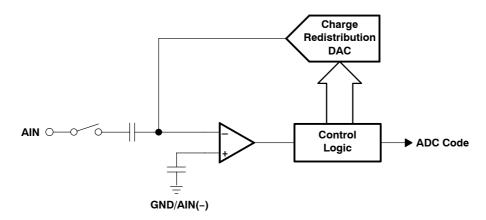


Figure 1. Simplified SAR Circuit

serial interface

OUTPUT DATA FORMAT				
MSB	LSB			
D15-D4	D3-D0			
Conversion result (OD11-OD0)	Don't care			

The output data format is binary (unipolar straight binary).

binary

Zero-scale code = 000h, Vcode = GND Full-scale code = FFFh, Vcode = V_{REF} - 1 LSB

pseudo-differential inputs

The TLV2545 operates in pseudo-differential mode. The inverted input is available on pin 5. It can have a maximum input ripple of ± 0.2 V. This is normally used for ground noise rejection.

control and timing

start of the cycle

Each cycle may be started by either \overline{CS} , FS, or a combination of both. The internal state machine requires one SCLK high-to-low transition to determine the state of these control signals so internal blocks can be powered up in an active cycle. Special care to SPI mode is necessary. Make sure there is at least one SCLK whenever \overline{CS} (pin 1) is high to ensure proper operation.

TLV2541

- Control via CS (FS = 1 at the falling edge of CS)—The falling edge of CS is the start of the cycle. The MSB should be read on the first falling SCLK edge after CS is low. Output data changes on the rising edge of SCLK. This is typically used for a microcontroller with an SPI interface, although it can also be used for a DSP. The microcontroller SPI interface should be programmed for CPOL = 0 (serial clock referenced to ground) and CPHA = 1 (data is valid on the falling edge of the serial clock). At least one falling edge transition on SCLK is needed whenever CS is brought high.
- Control via FS (CS is tied/held low)—The MSB is presented after the rising edge of FS. The falling edge
 of FS is the start of the cycle. The MSB should be read on the first falling edge of SCLK after FS is low. This
 is the typical configuration when the ADC is the only device on the DSP serial port.



control and timing (continued)

Control via both CS and FS—The MSB is presented after the falling edge of CS. The falling edge of FS is
the start of the sampling cycle. The MSB should be read on the first falling SCLK edge after FS is low. Output
data changes on the rising edge of SCLK. This configuration is typically used for multiple devices connected
to a TMS320 DSP.

TLV2542/5

All control is provided using \overline{CS} (pin 1) on the TLV2542 and TLV2545. The cycle is started on the falling edge transition provided by either a \overline{CS} signal from an SPI microcontroller or FS signal from a TMS320 DSP. Timing is similar to the TLV2541, with control via \overline{CS} only.

TLV2542 channel MUX reset cycle

The TLV2542 uses \overline{CS} to reset the analog input multiplexer. A short active \overline{CS} cycle (4 to 7 SCLKs) resets the MUX to AIN0. When the \overline{CS} cycle time is greater than 7 SCLKs in duration, as in the case for a complete conversion cycle (\overline{CS} is low for 16 SCLKs plus maximum conversion time), the MUX toggles to the next channel (see Figure 4 for timing). One dummy conversion cycle is recommended after power up before attempting to reset the MUX.

sampling

The converter sample time is 12 SCLKs in duration, beginning on the fifth SCLK received after the converter has received a high-to-low \overline{CS} transition (or a high-to-low FS transition for the TLV2541).

conversion

The TLV2541, TLV2542, and TLV2545 complete conversions in the following manner. The conversion is started after the 16th SCLK falling edge and takes 3.5 μ s to complete. Enough time (for conversion) should be allowed before a rising \overline{CS} or FS edge so that no conversion is terminated prematurely.

TLV2542 input channel selection is toggled on each rising $\overline{\text{CS}}$ edge. The MUX channel can be reset to AlN0 via $\overline{\text{CS}}$ as described in the earlier section and in Figure 4. The input is sampled for 12 SCLKs, converted, and the result is presented on SDO during the next cycle. Care should also be taken to allow enough time between samples to avoid prematurely terminating the cycle, which occurs on a rising $\overline{\text{CS}}$ transition if the conversion is not complete.

The SDO data presented during a cycle is the result of the conversion of the sample taken during the previous cycle.

timing diagrams/conversion cycles

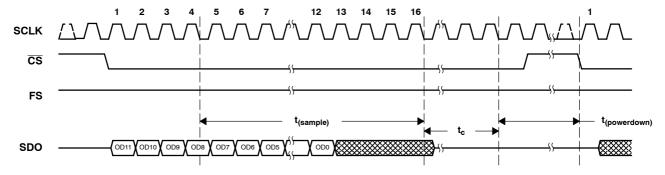


Figure 2. TLV2541 Timing: Control via CS (FS = 1)



timing diagrams/conversion cycles (continued)

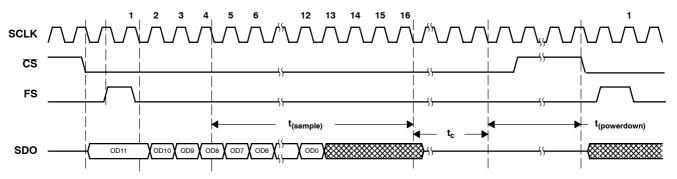


Figure 3. TLV2541 Timing: Control via $\overline{\text{CS}}$ and FS or FS Only

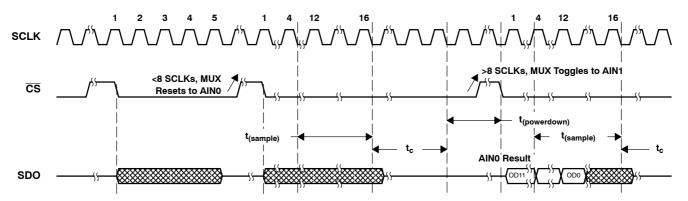


Figure 4. TLV2542 Reset Timing

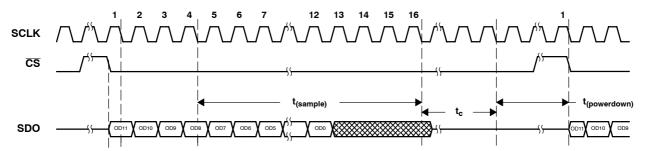


Figure 5. TLV2542 and TLV2545 Timing

using CS as the FS input

When interfacing the TLV2541 with the TMS320 DSP, the FSR signal from the DSP may be connected to the $\overline{\text{CS}}$ input if this is the only device on the serial port. This saves one output terminal from the DSP. (Output data changes on the falling edge of SCLK. This is the default configuration for the TLV2542 and TLV2545.)



TLV2541, TLV2542, TLV2545 2.7-V TO 5.5-V, LOW-POWER, 12-BIT, 140/200 KSPS, SERIAL ANALOG-TO-DIGITAL CONVERTERS WITH AUTOPOWER DOWN

SLAS245E -MARCH 2000 - REVISED APRIL 2010

using CS as the FS input (continued)

SCLK and conversion speed

The input frequency of SCLK can range from 100 kHz to 20 MHz maximum. The ADC conversion uses a separate internal oscillator with a minimum frequency of 4 MHz. The conversion cycle takes 14 internal oscillator clocks to complete. This leads to a 3.5- μ s conversion time. For a 20-MHz SCLK, the minimum total cycle time is given by: 16x(1/20M)+14x(1/4M)+ one SCLK = 4.35 μ s. An additional SCLK is added to account for the required \overline{CS} and/or FS high time. These times specify the minimum cycle time for an active \overline{CS} or FS signal. If violated, the conversion terminates, invalidating the next data output cycle. Table 1 gives the maximum SCLK frequency for a given supply voltage and operational mode.

control via pin 1 (CS, SPI interface)

All devices are compatible with this mode operation. A falling \overline{CS} initiates the cycle (for TLV2541, the FS input is tied to V_{DD}). \overline{CS} remains low for the entire cycle time (sample+convert+one SCLK) and can then be released.

NOTE:

IMPORTANT: A single SCLK is required whenever $\overline{\text{CS}}$ is high.

control via pin 1 (CS, DSP interface)

All devices are compatible with this mode of operation. The FS signal from a DSP is connected directly to the \overline{CS} input of the ADC. A falling edge on the \overline{CS} input initiates the cycle. (For the TLV2541, the FS input can be tied to V_{DD} , although better performance can be achieved when using the FS input for control. Refer to the next section.) The \overline{CS} input should remain low for the entire cycle time (sample+convert+one SCLK) and can then be released.

NOTE:

IMPORTANT: A single SCLK is required whenever $\overline{\text{CS}}$ is high. This should be of little consequence, since SCLK is normally always present when interfacing with a DSP.

control via pin 1 and pin 7 (CS and FS or FS only, DSP interface)

Only the TLV2541 is compatible with this mode of operation. The $\overline{\text{CS}}$ input to the ADC can be controlled via a general-purpose I/O pin from the DSP. The FS signal from the DSP is connected directly to the FS input of the ADC. A falling edge on $\overline{\text{CS}}$, if used, releases the MSB on the SDO output. When $\overline{\text{CS}}$ is not used, the rising FS edge releases the MSB. The falling edge on the FS input while SCLK is high initiates the cycle. The $\overline{\text{CS}}$ and FS inputs should remain low for the entire cycle time (sample+convert+one SCLK) and can then be released.

reference voltage

An external reference is applied via V_{REF} . The voltage level applied to this pin establishes the upper limit of the analog inputs to produce a full-scale reading. The value of V_{REF} and the analog input should not exceed the positive supply or be less than GND, consistent with the specified absolute maximum ratings. The digital output is at full scale when the input signal is equal to or higher than V_{REF} and at zero when the input signal is equal to or lower than GND.

power down and power up

Autopower down is built into these devices in order to reduce power consumption. The actual power savings depends on the inactive time between cycles and the power supply (loading) decoupling/storage capacitors. Power-down takes effect immediately after the conversion is complete. This is fast enough to provide some power savings between cycles with longer than 1 SCLK inactive time. The device power goes down to $5~\mu$ A within $0.5~\mu$ s. To achieve the lowest power-down current (deep powerdown) of $1~\mu$ A requires 2-ms inactive time between cycles. The power-down state is initiated at the end of conversion. These devices wake up immediately at the next falling edge of $\overline{\text{CS}}$ or the rising edge of FS.



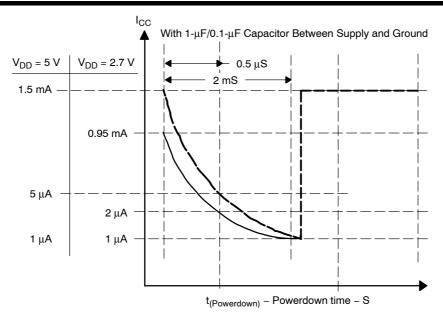


Table 1. Modes of Operation and Data Throughput

CONTROL PIN(s)/DEVICE	MAX SCI (50/50 du	` '	APPROXIMATE CONVERSION THROUGHPUT (ksps)					
	V _{DD} = 2.7 V	V V _{DD} = 4.5 V V _{DD} = 2		V _{DD} = 4.5 V				
CS control only (TLV2541 only)								
For SPI interface [†]	10	15	175	200				
For DSP interface (Use CS as FS)‡	5	8	140	175				
CS and FS control (TLV2541 only) [§]								
DSP interface	15	20	200	200				

[†] See Figure 29(a).

absolute maximum ratings over operating free-air temperature (unless otherwise noted)[¶]

Supply voltage range, GND to V _{DD}	
Analog input voltage range	–0.3 V to V_{DD} + 0.3 V
Reference input voltage	V _{DD} + 0.3 V
Digital input voltage range	
Operating virtual junction temperature range, T _J	–40°C to 150°C
Operating free-air temperature range, T _A : C	0°C to 70°C
I	–40°C to 85°C
Storage temperature range, T _{stq}	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



[‡] See Figure 29(b).

[§] See Figure 29(c).

TLV2541, TLV2542, TLV2545 2.7-V TO 5.5-V, LOW-POWER, 12-BIT, 140/200 KSPS, SERIAL ANALOG-TO-DIGITAL CONVERTERS WITH AUTOPOWER DOWN SLAS245E - MARCH 2000 - REVISED APRIL 2010

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{DD}		2.7	3.3	5.5	V
Positive external reference voltage input, V _{REFP} (see Note 1)				V_{DD}	V
Analog input voltage (see Note 1)				V_{DD}	V
High level control input voltage, V _{IH}					V
Low-level control input voltage, V _{IL}			0.6	V	
Setup time, CS falling edge before first SCLK falling edge,	V _{DD} = REF = 4.5 V	40			
t _{su(CSL-SCLKL)}	V _{DD} = REF = 2.7 V	70			ns
Hold time, CS falling edge after SCLK falling edge, th(SCLKL-CSL)		5			ns
Delay time, delay from CS falling edge to FS rising edge, t _{d(CSL-FSH)} (TLV2541 only)				7	SCLKs
Setup time, FS rising edge before SCLK falling edge, t _{su(FSH-SCLKL)} (TLV2541 only)					SCLKs
Hold time, FS high after SCLK falling edge, t _{h(SCLKL-FSL)} (TLV2541	only)			0.65	SCLKs
Pulse width CS high time, t _{w(H_CS)}		100			ns
Pulse width FS high time, t _{w(H_FS)} (TLV2541 only)		0.75			SCLKs
SCLK cycle time, V _{DD} = 3.6 V to 2.7 V, t _{c(SCLK)} (maximum tolerance of 40/60 duty cycle)				10000	ns
SCLK cycle time, V _{DD} = 5.5 V to 4.5 V, t _{c(SCLK)} (maximum tolerance of 40/60 duty cycle)				10000	ns
Pulse width low time, t _{w(L SCLK)}				0.6	SCLK
Pulse width high time, t _{w(H SCLK)}				0.6	SCLK
Hold time, hold from end of conversion to $\overline{\text{CS}}$ high, $t_{\text{h(EOC-CSH)}}$ (EOC i time, t_{c})	s internal, indicates end of conversion		0.05		μs
Active CS cycle time to reset internal MUX to AIN0, t _(reset cycle) (TLV	(2542 only)	4		7	SCLKs
B	V _{DD} = REF = 4.5 V, 25-pF load			40	
Delay time, delay from $\overline{\text{CS}}$ falling edge to SDO valid, $t_{\text{d(CSL-SDOV)}}$	V _{DD} = REF = 2.7 V, 25-pF load	0 V _{DD} 2.1 0.6 40 70 5 0.5 7 0.35 0.65 100 0.75 90 10000 50 10000 0.4 0.6 0.4 0.6 errsion 0.05 4 7 ad 40 ad 70 ad 1 ad 11 ad 11 ad 21 ad 30	ns		
Delay time, delay from FS falling edge to SDO valid, t _{d(FSL-SDOV)}	V _{DD} = REF = 4.5 V, 25-pF load			1	no
(TLV2541 only)	V _{DD} = REF = 2.7 V, 25-pF load		7 0.65 10000 10000 0.6 0.6 0.05 7 40 70 1 11 21 30 60 2.6 3.5	ns	
Delay time, delay from SCLK rising edge to SDO valid,	V _{DD} = REF = 4.5 V, 25-pF load			11	ne
^t d(SCLKH-SDOV)	V _{DD} = REF = 2.7 V, 25-pF load			21	ns
Delay time, delay from 17th SCLK rising edge to SDO 3-state,	V _{DD} = REF = 4.5 V, 25-pF load			30	ns
^t d(SCLK17H-SDOZ)	V_{DD} = REF = 2.7 V, 25-pF load			60	115
Conversion time, t _c	Conversion clock = internal oscillator	2.1	2.6	3.5	μs
Sampling time, t _(sample)	See Note 2	300			ns
Operating free-air temperature, T_{Δ}	TLV2541/2/5C	0		70	°C
Operating nee-an temperature, 14	TLV2541/2/5I	-40	·	85	

NOTES: 1. Analog input voltages greater than that applied to V_{REF} convert as all ones (11111111111), while input voltages less than that applied to GND convert as all zeros(000000000000).

2. Minimal $t_{(sample)}$ is given by 0.9×50 pF \times (R_S + 0.5 k Ω), where R_S is the source output impedance.

TLV2541, TLV2542, TLV2545 2.7-V TO 5.5-V, LOW-POWER, 12-BIT, 140/200 KSPS, SERIAL ANALOG-TO-DIGITAL CONVERTERS WITH AUTOPOWER DOWN SLAS245E -MARCH 2000 - REVISED APRIL 2010

electrical characteristics over recommended operating free-air temperature range, V_{DD} = V_{REF} = 2.7 V to 5.5 V (unless otherwise noted)

	PARAMETER	TEST	CONDITIONS	MIN	TYP [†]	MAX	UNIT
	High-level output voltage		V_{DD} = 5.5 V, I_{OH} = -0.2 mA at 30-pF load				.,
V _{OH}	Hign-level output voltage	V _{DD} = 2.7 V, I _{OH} =	V _{DD} = 2.7 V, I _{OH} = -20 μA at 30-pF load				V
V	La la da la Labara	V _{DD} = 5.5 V, I _{OL} =	0.8 mA at 30-pF load			0.4	.,
V _{OL}	Low-level output voltage	V _{DD} = 2.7 V, I _{OL} = 20 μA at 30-pF load				0.1	V
	Off-state output current	$V_O = V_{DD}$	00 V		1	2.5	
loz	(high-impedance-state)	V _O = 0	$\overline{CS} = V_{DD}$		-1	-2.5	μΑ
I _{IH}	High-level input current	$V_I = V_{DD}$	•		0.005	2.5	μА
I _{IL}	Low-level input current	V _I = 0 V			-0.00 5	2.5	μА
	0	70 -1 0 1/	V _{DD} = 4.5 V to 5.5 V		1.3	1.5	A
Icc	Operating supply current	CS at 0 V	$V_{DD} = 2.7 \text{ V to } 3.3 \text{ V}$		0.85	0.95	mA
	Autopower-down current t _(powerdown) ≥ 0.5 µs	For all digital inputs, $0 \le V_1 \le 0.3 \text{ V}$ or $V_1 \ge V_{DD} - 0.3 \text{ V}$, $SCLK = 0$, $V_{DD} = 4.5 \text{ V}$ to 5.5 V, Ext ref				5	μΑ
	(powerdown)	V _{DD} = 2.7 V to 3.3 V, Ext ref				2	
ICC(AUTOPWDN)	Deep autopower-down current $t_{(powerdown)} \ge 2 \text{ ms}$	For all digital inputs, $0 \le V_1 \le 0.3 \text{ V}$ or $V_1 \ge V_{DD} - 0.3 \text{ V}$, $SCLK = 0$, $V_{DD} = 4.5 \text{ V}$ to 5.5 V, Ext ref				1	μА
	(powerdown)	V _{DD} = 2.7 V to 3.3 V				1	
	Selected analog input channel	Selected channel at V _{DD}				1	
	leakage current	Selected channel	Selected channel at 0 V			-1	μ A
		Analog inputs		20	45	50	_
C _i	Input capacitance	Control Inputs			5	25	pF
	la a la constata da	V _{DD} = 5.5 V				500	0
	Input on resistance	V _{DD} = 2.7 V				600	Ω
	Autopower down				0.5		SCLK

[†] All typical values are at $V_{DD} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

TLV2541, TLV2542, TLV2545 2.7-V TO 5.5-V, LOW-POWER, 12-BIT, 140/200 KSPS, SERIAL ANALOG-TO-DIGITAL CONVERTERS WITH AUTOPOWER DOWN

SLAS245E -MARCH 2000 - REVISED APRIL 2010

ac specifications (f_i = 20 kHz)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
CINIAD	Cinnal to mains water a distantian	200 KSPS, V _{DD} = V _{REF} = 5.5 V	70	72		J.		
SINAD	Signal-to-noise ratio +distortion	150 KSPS, V _{DD} = V _{REF} = 2.7 V	68	71		dB		
TUD	Total because and adiabatics	200 KSPS, V _{DD} = V _{REF} = 5.5 V		-84	-80	J.		
THD	Total harmonic distortion	150 KSPS, $V_{DD} = V_{REF} = 2.7 \text{ V}$		-84	-80	dB		
ENOD	Effective and acceptable	200 KSPS, V _{DD} = V _{REF} = 5.5 V		11.8		Dit		
ENOB	Effective number of bits	150 KSPS, V _{DD} = V _{REF} = 2.7 V		11.6		Bits		
OFDD	On the office discourse	200 KSPS, V _{DD} = V _{REF} = 5.5 V		-84	-80	Į.		
SFDR	Spurious free dynamic range	150 KSPS, V _{DD} = V _{REF} = 2.7 V		-84	-80	dB		
Analog	Analog Input							
	Full-power bandwidth, -3 dB			1		MHz		
	Full-power bandwidth, -1 dB			500		kHz		

external reference specifications

	PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
Re	eference input voltage	V _{DD} = 2.7 V to 5.5 V			2		V_{DD}	V
		V 55V	CS = 1,	SCLK = 0	100			МΩ
De	.foresee in a discount in a selection	V _{DD} = 5.5 V	$\overline{\text{CS}} = 0,$	SCLK = 20 MHz	20	25		kΩ
He	eference input impedance	V 07V	CS = 1,	SCLK = 0	100			$M\Omega$
		V _{DD} = 2.7 V	$\overline{\text{CS}} = 0,$	SCLK = 20 MHz	20	25		kΩ
Po	eforonce ourront	$V_{DD} = V_{REF} = 5.5 V$,	$\overline{\text{CS}} = 0,$	SCLK = 20 MHz		100	400	μА
ne	Reference current	$V_{DD} = V_{REF} = 2.7 V$,	CS = 0,	SCLK = 20 MHz		50	200	μΑ
			CS = 1,	SCLK = 0	5		15	1
.	f	$V_{DD} = V_{REF} = 5.5 V$	$\overline{\text{CS}} = 0,$	SCLK = 20 MHz	20	45	50	
Reference input capacitance	eterence input capacitance	V V 07V	CS = 1,	SCLK = 0	5		15	pF
		$V_{DD} = V_{REF} = 2.7 V$	<u>CS</u> = 0,	SCLK = 20 MHz	20	45	50	
V _{REF} Re	eference voltage	$V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$					V_{DD}	V

dc specification, V_{DD} = V_{REF} = 2.7 V to 5.5 V, SCLK frequency = 20 MHz at 5 V, 15 MHz at 3 V (unless otherwise noted)

PARAMETER		TEST (TEST CONDITIONS			MAX	UNIT
INL	Integral linearity error (see Note 4)				±0.6	±1	LSB
DNL	Differential linearity error	See Note 3			±0.5	±1	LSB
	Office Leaves (see Note 5)	0 - 1 1 - 0	TLV2541/42			±1.5	LOD
Eo	Offset error (see Note 5)	serror (see Note 5) See Note 3	TLV2545			±2.5	LSB
_	0 : (N : 5)		TLV2541/42			±2	1.00
E _G	Gain error (see Note 5)	See Note 3	TLV2545			±5	LSB
_	T	0 11 0	TLV2541/42			±2	1.00
Et	Gain error (see Note 5) See Note 3 Total unadjusted error (see Note 6) See Note 3	TLV2545			±5	LSB	

NOTES: 3. Analog input voltages greater than that applied to V_{REF} convert as all ones (111111111111).

- 4. Linear error is the maximum deviation from the best straight line through the A/D transfer characteristics.
- 5. Zero error is the difference between 000000000000 and the converted output for zero input voltage: full-scale error is the difference between 11111111111 and the converted output for full-scale input voltage.
- 6. Total unadjusted error comprises linearity, zero, and full-scale errors.



PARAMETER MEASUREMENT INFORMATION

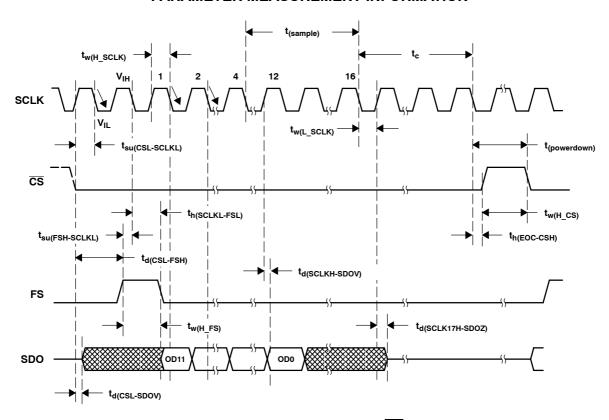


Figure 6. TLV2541 Critical Timing (Control via CS and FS or FS only)

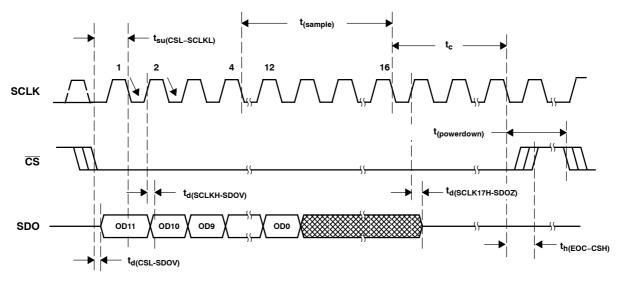


Figure 7. TLV2541 Critical Timing (Control via CS only, FS = 1)



PARAMETER MEASUREMENT INFORMATION

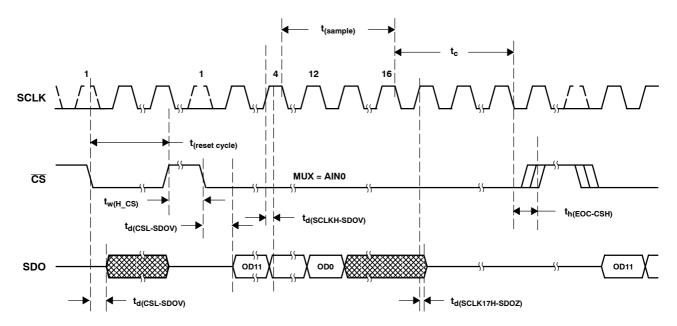


Figure 8. TLV2542 Reset Cycle Critical Timing

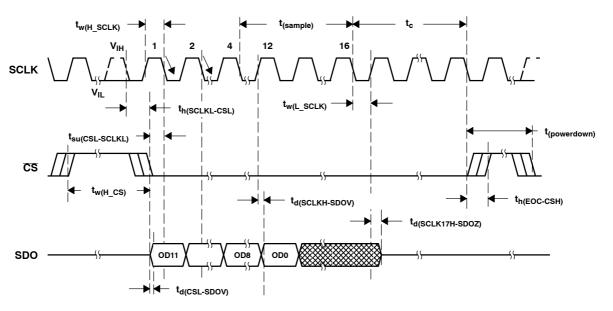
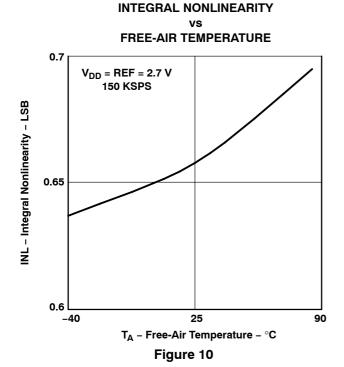
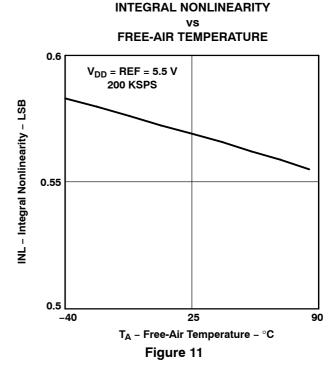
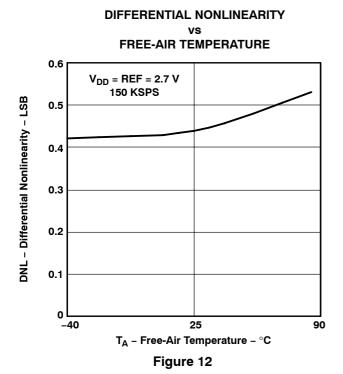


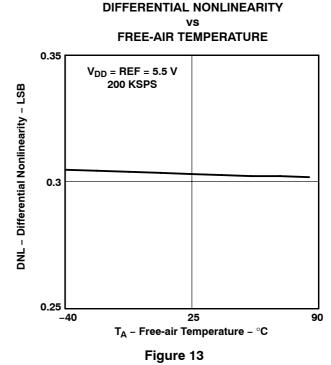
Figure 9. TLV2542 and TLV2545 Conversion Cycle Critical Timing

TYPICAL CHARACTERISTICS

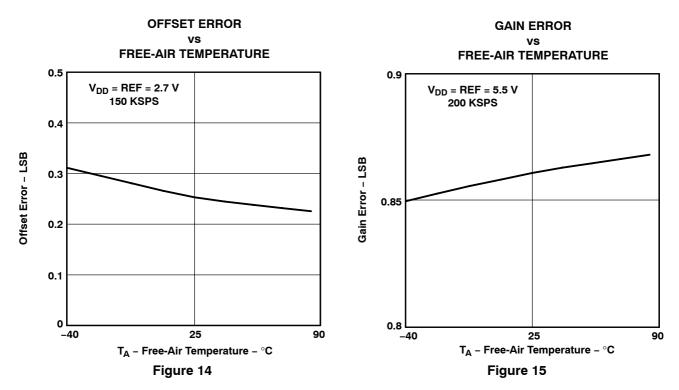








TYPICAL CHARACTERISTICS



SUPPLY CURRENT FREE-AIR TEMPERATURE

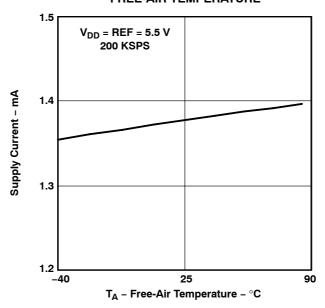


Figure 16

TYPICAL CHARACTERISTICS

INTEGRAL NONLINEARITY ERROR vs DIGITAL OUTPUT CODES

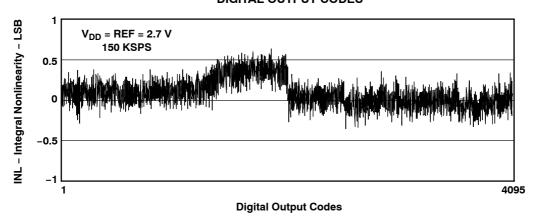


Figure 17

DIFFERENTIAL NONLINEARITY ERROR VS

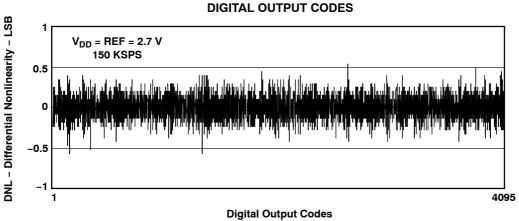
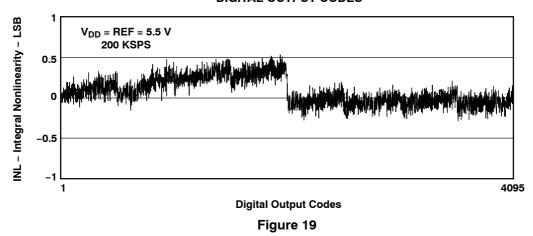


Figure 18



TYPICAL CHARACTERISTICS

INTEGRAL NONLINEARITY ERROR vs DIGITAL OUTPUT CODES



DIFFERENTIAL NONLINEARITY ERROR VS

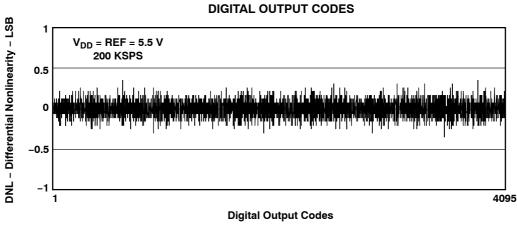


Figure 20

TYPICAL CHARACTERISTICS

2048 POINTS FAST FOURIER TRANSFORM (FFT)

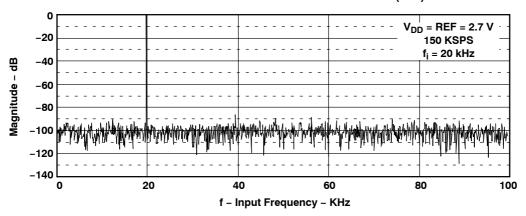


Figure 21

2048 POINTS FAST FOURIER TRANSFORM (FFT)

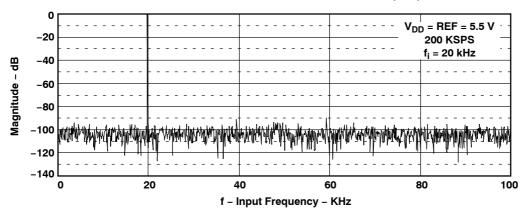
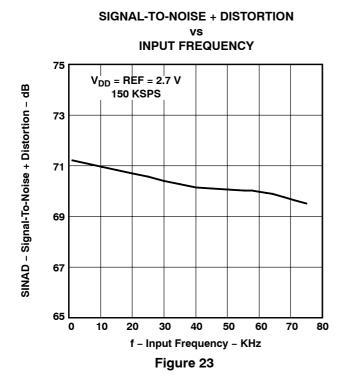
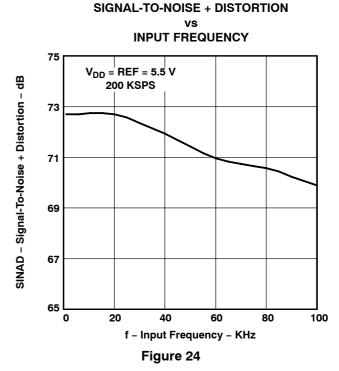


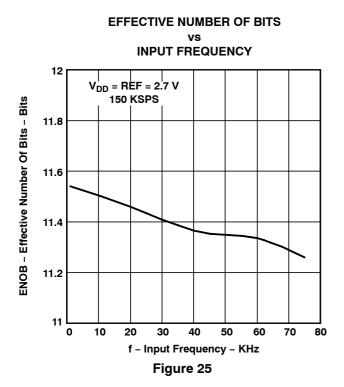
Figure 22

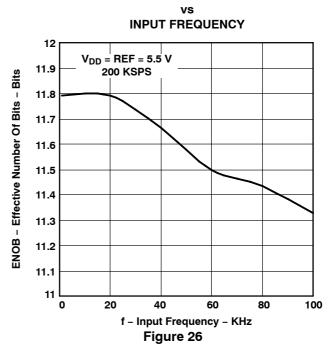
TYPICAL CHARACTERISTICS





EFFECTIVE NUMBER OF BITS





TYPICAL CHARACTERISTICS

TOTAL HARMONIC DISTORTION vs INPUT FREQUENCY

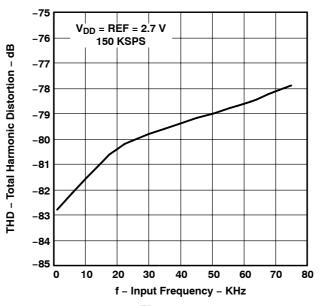
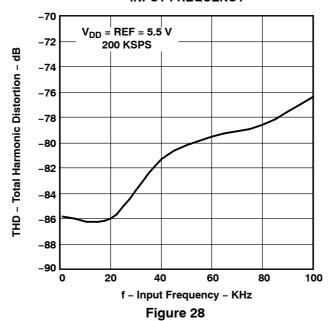


Figure 27

TOTAL HARMONIC DISTORTION

vs INPUT FREQUENCY



APPLICATION INFORMATION

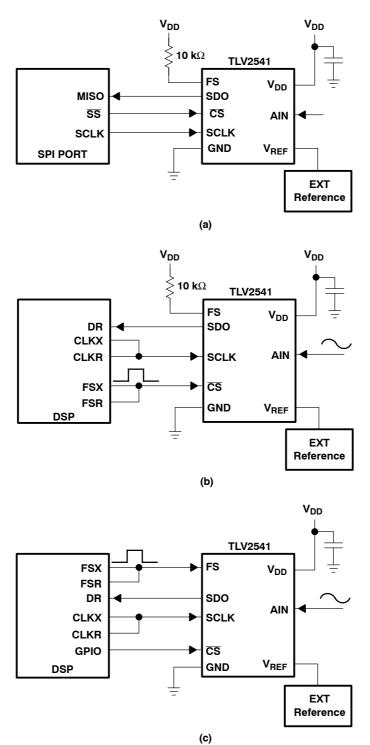


Figure 29. Typical TLV2541 Interface to a TMS320 DSP



APPLICATION INFORMATION

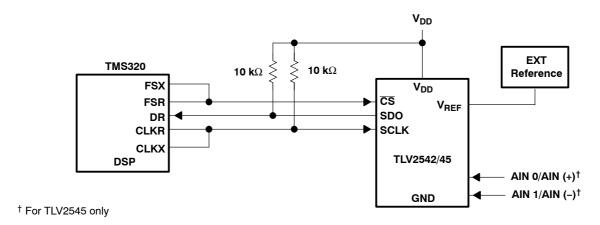


Figure 30. Typical TLV2542/45 Interface to a TMS320 DSP







26-Aug-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2541CDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	AGZ	Samples
TLV2541CDGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	AGZ	Samples
TLV2541CDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	AGZ	Samples
TLV2541CDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	AGZ	Samples
TLV2541ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25411	Samples
TLV2541IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25411	Samples
TLV2541IDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	АНА	Samples
TLV2541IDGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	АНА	Samples
TLV2541IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	АНА	Samples
TLV2541IDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	АНА	Samples
TLV2541IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25411	Samples
TLV2541IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25411	Samples
TLV2542CDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	АНВ	Samples
TLV2542CDGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	АНВ	Samples
TLV2542CDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	АНВ	Samples
TLV2542CDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	АНВ	Samples
TLV2542ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25421	Samples





26-Aug-2013

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
TLV2542IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25421	Sample
TLV2542IDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AHC	Sample
TLV2542IDGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AHC	Sample
TLV2542IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AHC	Sample
TLV2542IDGKRG4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AHC	Sample
TLV2542IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25421	Sample
TLV2542IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25421	Sample
TLV2545CDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	AHD	Sample
TLV2545CDGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	AHD	Sample
TLV2545ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25451	Sample
TLV2545IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	25451	Sample
TLV2545IDGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AHE	Sample
TLV2545IDGKG4	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	AHE	Sample
TLV2545IDGKRG4	OBSOLETE	VSSOP	DGK	8		TBD	Call TI	Call TI	-40 to 85	AHE	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

26-Aug-2013

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

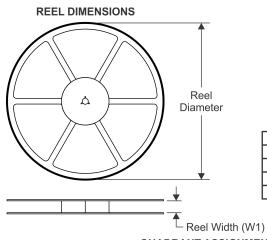
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

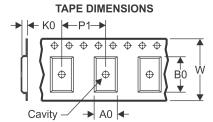
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 12-Aug-2013

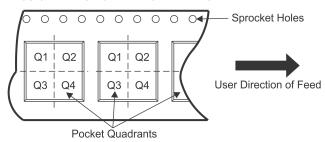
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

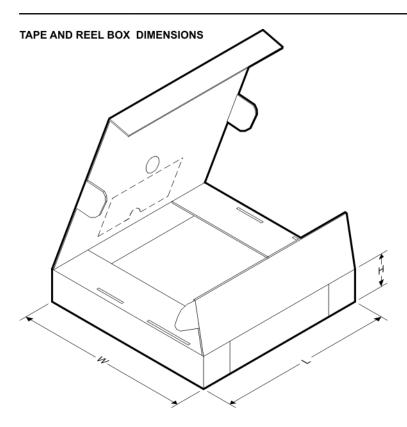
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2541CDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2541IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2541IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2542CDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2542IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2542IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

www.ti.com 12-Aug-2013

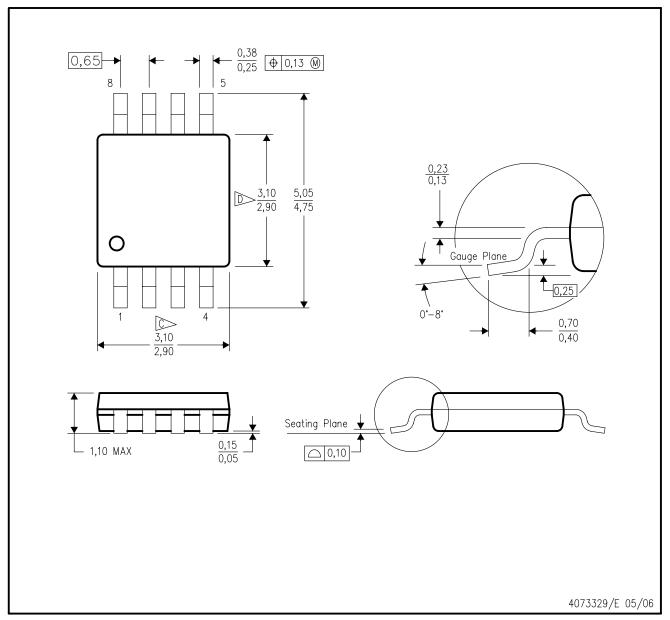


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2541CDGKR	VSSOP	DGK	8	2500	367.0	367.0	35.0
TLV2541IDGKR	VSSOP	DGK	8	2500	367.0	367.0	35.0
TLV2541IDR	SOIC	D	8	2500	367.0	367.0	35.0
TLV2542CDGKR	VSSOP	DGK	8	2500	367.0	367.0	35.0
TLV2542IDGKR	VSSOP	DGK	8	2500	367.0	367.0	35.0
TLV2542IDR	SOIC	D	8	2500	367.0	367.0	35.0

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



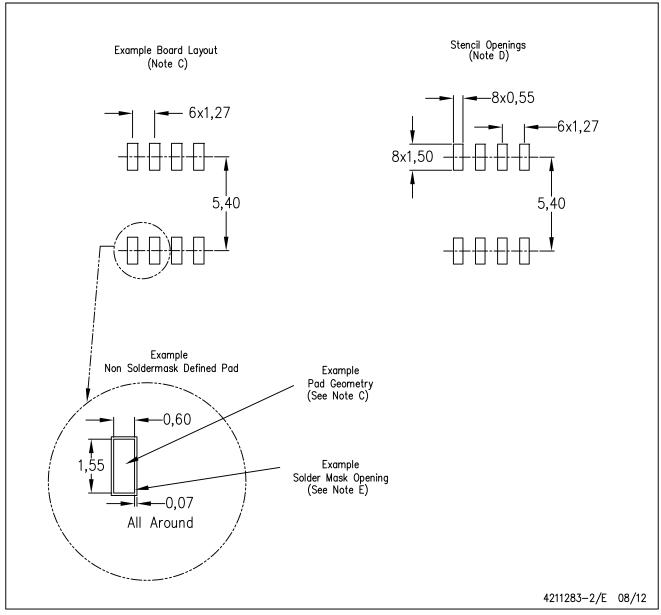
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers <u>microcontroller.ti.com</u> Video and Imaging <u>www.ti.com/video</u>

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>